- **Function, Pinout, and Drive Compatible** With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of **Equivalent FCT Functions**
- **Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics**
- I_{off} Supports Partial-Power-Down Mode Operation
- **Matched Rise and Fall Times**
- Fully Compatible With TTL Input and **Output Logic Levels**
- **Dual 1-of-8 Decoder With Enables**
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- CY54FCT138T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT138T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

CY74FCT138T...Q OR SO PACKAGE (TOP VIEW) 16 NCC A_0 A_1 \overline{O}_0 15**П** <u>А</u>2 **[**] з O_1 14Π <u>=</u> ₫ 13**N** E₂ \overline{O}_3 12 E₃ 6 \overline{O}_4 11 ∏

CY54FCT138T . . . D PACKAGE

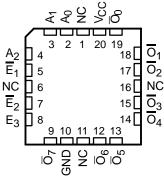
CY54FCT138T . . . L PACKAGE (TOP VIEW)

10 O₅

9 \overline{O}_6

O₇ [

GND ∏8



NC - No internal connection

description

The 'FCT138T devices are 1-of-8 decoders. These devices accept three binary weighted inputs (A₀, A₁, A₂) and, when enabled, provide eight mutually exclusive active-low outputs $(\overline{O}_0 - \overline{O}_7)$. The 'FCT138T devices feature three enable inputs: two active low $(\overline{E}_1, \overline{E}_2)$ and one active high (E_3) .

All outputs are high unless \overline{E}_1 and \overline{E}_2 are low and E_3 is high. This multiple-enable function allows easy parallel expansion of the device to a 1-of-32 (five lines to 32 lines) decoder with just four 'FCT138T devices and one inverter.

These devices are fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

PIN DESCRIPTION

NAME	DESCRIPTION
Α	Address inputs
$\overline{E}_1, \overline{E}_2$	Enable inputs (active low)
E ₃	Enable input (active high)
Ō	Outputs



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

TA	PACI	(AGE [†]	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	5	CY74FCT138CTQCT	FT138-3
	SOIC - SO	Tube	5	CY74FCT138CTSOC	FCT138C
	3010 - 30	Tape and reel	5	CY74FCT138CTSOCT	FC1136C
–40°C to 85°C	QSOP – Q	Tape and reel	5.8	CY74FCT138ATQCT	FT138-1
	SOIC - SO	Tube	5.8	CY74FCT138ATSOC	FCT138A
	3010 = 30	Tape and reel	5.8	CY74FCT138ATSOCT	FOTISOA
	QSOP – Q	Tape and reel	9	CY74FCT138TQCT	FT138
	LCC – L	Tube	6	CY54FCT138CTLMB	
–55°C to 125°C	LCC – L	Tube	12	CY54FCT138TLMB	
	CDIP – D	Tube	12	CY54FCT138TDMB	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

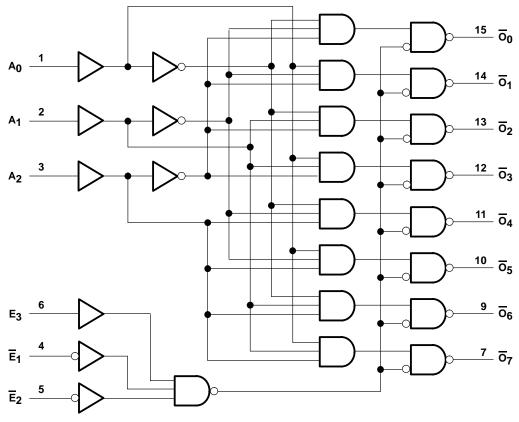
FUNCTION TABLE

INPUTS						OUTPUTS							
E ₁	E ₂	E ₃	A ₀	A ₁	A ₂	O ₀	<u>0</u> 1	02	03	04	05	06	07
Н	Х	Χ	Χ	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Х	Н	X	X	Χ	X	Н	Н	Н	Н	Н	Н	Н	Н
Х	X	L	Χ	Χ	X	Н	Н	Н	Н	Н	Н	Н	Н
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
L	L	Н	Н	L	L	Н	L	Н	Н	Н	Н	Н	Н
L	L	Н	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
L	L	Н	Н	Н	L	Н	Н	Н	L	Н	Н	Н	Н
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н
L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = High logic level, L = Low logic level, X = Don't care



logic diagram (positive logic)



Pin numbers shown are for the D, Q, and SO packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	0.5 V to 7 V
DC output voltage range	0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ _{JA} (see Note 1): Q package	90°C/W
SO package	
Ambient temperature range with power applied, T _A	-65°C to 135°C
Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.



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recommended operating conditions (see Note 2)

		CY54FCT138T			CY	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			8.0			0.8	V
loh	High-level output current			-12			-32	mA
lOL	Low-level output current			32			64	mA
TA	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	C	/54FCT13	188	CY						
PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†] MAX		UNIT			
	$V_{CC} = 4.5 \text{ V}, \qquad I_{IN} = -18 \text{ mA}$		-0.7	-1.2				V			
VIK	$V_{CC} = 4.75 \text{ V}, \qquad I_{IN} = -18 \text{ mA}$					-0.7	-1.2	V			
	$V_{CC} = 4.5 \text{ V}, \qquad I_{OH} = -12 \text{ mA}$	2.4	3.3								
Vон	V _{CC} = 4.75 V I _{OH} = -32 mA				2			V			
	$I_{OH} = -15 \text{ mA}$				2.4	3.3					
\/a:	$V_{CC} = 4.5 \text{ V}, \qquad I_{OL} = 32 \text{ mA}$		0.3	0.55				V			
VOL	$V_{CC} = 4.75 \text{ V}, \qquad I_{OL} = 64 \text{ mA}$					0.3	0.55	V			
V_{hys}	All inputs		0.2			0.2		٧			
	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = V_{CC}$			5				μA			
li .	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = V_{CC}$						5	5 47			
lu i	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$			±1				μA			
ΊΗ	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 2.7 \text{ V}$						±1				
IIL	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$			±1				μA			
'IL	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} = 0.5 \text{ V}$						±1	μΛ			
last.	$V_{CC} = 5.5 \text{ V}, \qquad V_{OUT} = 0 \text{ V}$	-60	-120	-225				mA			
los‡	$V_{CC} = 5.25 \text{ V}, \qquad V_{OUT} = 0 \text{ V}$				-60	-120	-225	ША			
l _{off}	$V_{CC} = 0 \text{ V}, \qquad V_{OUT} = 4.5 \text{ V}$			±1			±1	μΑ			
Icc	$V_{CC} = 5.5 \text{ V}, \qquad V_{IN} \le 0.2 \text{ V}, \qquad V_{IN} \ge V_{CC} - 0.2 \text{ V}$	/	0.1	0.2				mA			
100	$V_{CC} = 5.25 \text{ V}, \qquad V_{IN} \le 0.2 \text{ V}, \qquad V_{IN} \ge V_{CC} - 0.2 \text{ V}$	/				0.1	0.2	ША			
Aloo	$V_{CC} = 5.5 \text{ V}, V_{IN} = 3.4 \text{ V}$, $f_1 = 0$, Outputs open		0.5	2				mA			
ΔICC	$V_{CC} = 5.25 \text{ V}, V_{IN} = 3.4 \text{ V}$, $f_1 = 0$, Outputs open					0.5	.5 2 m/				
1¶	V_{CC} = 5.5 V, Outputs open, One bit switching at 50% du cycle, $V_{IN} \le 0.2$ V or $V_{IN} \ge V_{CC} - 0.2$ V	ty	0.06	0.12				mA/			
^I CCD [¶]	V_{CC} = 5.25 V, Outputs open, One bit switching at 50% duty cycle, $V_{IN} \le 0.2$ V or $V_{IN} \ge V_{CC} - 0.2$ V					0.06	0.12	MHz			

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, Ios tests should be performed last.

[§] Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETER	TEST CONDITIONS			CY	54FCT13	8T	CY	UNIT		
PARAMETER	TEST CONDITIONS				TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
IC#	$V_{CC} = 5.5 \text{ V},$ Outputs open, Switch \overline{E}_1 , \overline{E}_2 , or	One output switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	E ₃	at 50% duty cycle	V _{IN} = 3.4 V or GND		1	2.4				mA
I.C.	$V_{CC} = 5.25 \text{ V},$ Outputs open, Switch \overline{E}_1 , \overline{E}_2 , or	One output switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	IIIA
	E ₃	at 50% duty cycle	V _{IN} = 3.4 V or GND					1	2.4	
C _i					5	10		5	10	pF
Co					9	12		9	12	pF

 $[\]overline{\dagger}$ Typical values are at V_{CC} = 5 V, T_A = 25°C.

Where:

IC = Total supply current

I_{CC} = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the ICC formula.

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY54FC	T138T	CY54FC1	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
^t PLH	۸	ō	1.5	12	1.5	6	ns
t _{PHL}	A	O	1.5	12	1.5	6	115
^t PLH	FF	ō	1.5	12.5	1.5	6.1	ns
t _{PHL}	\overline{E}_1 or \overline{E}_2	O	1.5	12.5	1.5	6.1	115
^t PLH	Eo	ō	1.5	12.5	1.5	6.1	nc
^t PHL	E3	J	1.5	12.5	1.5	6.1	ns

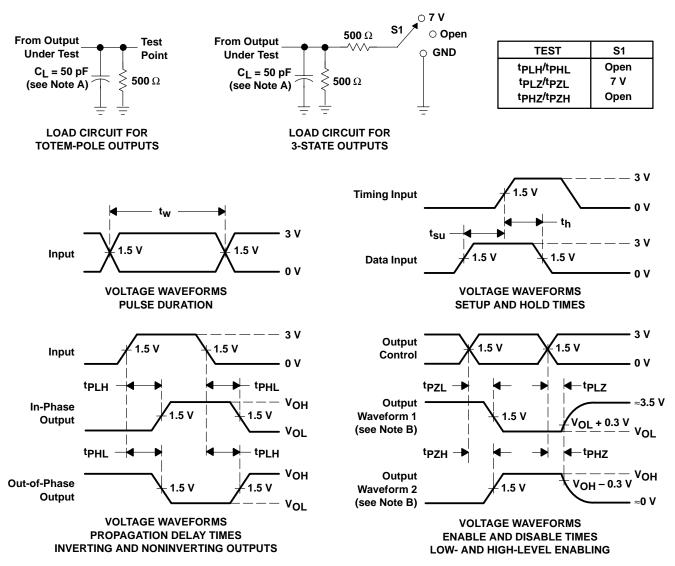
switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	T138T	CY74FC	Г138АТ	CY74FC1	T138CT	UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	А	ō	1.5	9	1.5	5.8	1.5	5	no
t _{PHL}		0	1.5	9	1.5	5.8	1.5	5	ns
^t PLH	EE	ō	1.5	9	1.5	5.9	1.5	5	20
^t PHL	\overline{E}_1 or \overline{E}_2	O	1.5	9	1.5	5.9	1.5	5	ns
^t PLH	E ₃	ō	1.5	9	1.5	5.9	1.5	5	20
tPHL				1.5	9	1.5	5.9	1.5	5



 $^{^{\#}}$ IC = ICC + \triangle ICC \times DH \times NT + ICCD (f₀/2 + f₁ \times N₁)

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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